

GIGALIGHT 400G OSFP-RHS DR4 500m Silicon Photonics Transceiver

Module

P/N: GOP-SI401DR4C

Features

- ✓ OSFP MSA and CMIS compliant
- ✓ Compliant to 802.3bs
- ✓ 4x106.25Gbps(53.125GBd PAM4)electrical interface
- ✓ 4x106.25Gbps(53.125GBd PAM4)optics architecture
- ✓ Power consumption <10W
- ✓ Maximum link length of 500m G.652 SMF with KP-FEC
- ✓ MPO-12 receptacles
- ✓ Built-in digital diagnostic functions
- ✓ Operating case temperature 0°C to +70°C
- ✓ 3.3V power supply voltage
- ✓ RoHS compliant(lead free)

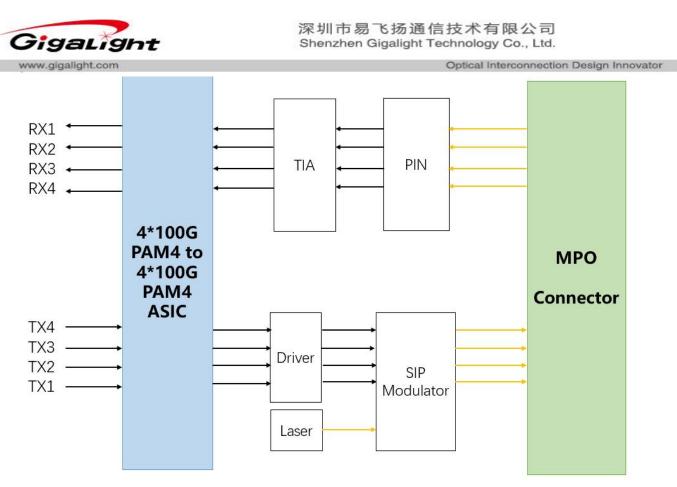
Applications

- ✓ Ethernet and Telecom
- ✓ Infiniband

Description

The Gigalight GOP-SI401DR4C is a transceiver module designed for 500m optical communication applications, and it is compliant to OSFP MSA, IEEE 802.3bs protocol. The silicon photonics transceiver is based on a new state-of-the-art silicon photonics (SiPh) platform. It uses SiPh chips that integrate a number of active and passive optoelectronic components, 3D packaging technology and industry-leading 7nm DSP chips. It is a cost-effective and lower power consumption solution for 400GBASE data center. It has been designed to meet the harshest external operating conditions including temperature, humidity and EMI interference. The module offers very high functionality and feature integration, accessible via a two-wire serial interface.







Absolute Maximum Ratings

Parameter	Symbol	Min	Мах	Unit
Supply Voltage	Vcc	-0.3	3.6	V
Input Voltage	Vin	-0.3	Vcc+0.3	V
Storage Temperature	Tst	-40	85	°C
Case Operating Temperature	Тор	0	70	°C
Humidity(non-condensing)	Rh	5	95	%

Recommended Operating Conditions

Parameter	Symbol	Min	Typical	Мах	Unit
Supply Voltage	Vcc	3.13	3.3	3.47	V
Operating Case temperature	Тса	0		70	°C
Data Rate Per Lane	fd		106.25		Gbit/s
Humidity	Rh	15		85	%
Power Dissipation	Pm			10	W



Electrical Specifications

Parameter	Symbol	Min	Typical	Мах	Unit
Differential input impedance	Zin	90	100	110	ohm
Differential Output impedance	Zout	90	100	110	ohm
Differential input voltage amplitude	ΔVin	900			mVp-p
Differential output voltage amplitude	ΔVout			900	mVp-p
Bit Error Rate	BER			2.4E-4	-
Transition Time		8			ps
Near-end Vertical Eye Closure over +/- 50 mUI (VEC)		12			UI
Near-end Vertical Eye Opening over +/- 50 mUI (VEO)		20			mV
Far-end Vertical Eye Closure over +/- 50 mUI (VEC)		12			UI
Far-end Vertical Eye Opening over +/- 50 mUI (VEO)		15			mV

Note:

- 1) BER=2.4E-4; PRBS31Q@53.125GBd. Pre-FEC
- 2) Differential input voltage amplitude is measured between TxnP and TxnN.
- 3) Differential output voltage amplitude is measured between RxnP and RxnN.

Optical Characteristics

Table 3 - Optical Characteristics

Parameter	Symbol	Min	Typical	Мах	Unit	Notes
	Transmitter					
Centre Wavelength	λc	1304.5		1317.5	nm	-
Side-mode suppression ratio	SMSR	30	-		dB	-
Average launch power, each lane	Pout	-2.9	-	4.0	dBm	-
Optical Modulation Amplitude(OMA outer), each lane	ОМА	-0.8	-	4.2	dBm	-



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Transmitter and dispersion eye closure for PAM4 (TDECQ),each lane	TDECQ			3.4	dB	
Extinction Ratio	ER	3.5	-	-	dB	-
Average launch power of OFF transmitter, each lane		-15	dB	-		
		Receive	r			
Centre Wavelength	λc	1304.5		1317.5	nm	-
Receiver Sensitivity in OMA outer	RXsen			-4.4	dBm	1
Average power at receiver , each lane input, each lane	Pin	-5.9		4	dBm	-
Receiver Reflectance				-26	dB	-
LOS Assert		-13			dBm	-
LOS De-Assert				-10	dBm	-
LOS Hysteresis		0.5			dB	-

Note:

1) Measured with conformance test signal at TP3 for BER = 2.4E-4 Pre-FEC



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Pin Description

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Pin#	Symbol	Description	Logic	Direction	Plug Sequence	Notes	
1	GND	Ground			1		
2	TX2p	Transmitter Data Non-Inverted	CML-I	Input from Host	3		
3	TX2n	Transmitter Data Inverted	CML-I	Input from Host	3		
4	GND	Ground			1		
5	TX4p	Transmitter Data Non-Inverted	CML-I	Input from Host	3		
6	TX4n	Transmitter Data Inverted	CML-I	Input from Host	3		
7	GND	Ground			1		
8	TX6p	Transmitter Data Non-Inverted	CML-I	Input from Host	3		
9	TX6n	Transmitter Data Inverted	CML-I	Input from Host	3		
10	GND	Ground			1		
11	TX8p	Transmitter Data Non-Inverted	CML-I	Input from Host	3		
12	TX8n	Transmitter Data Inverted	CML-I	Input from Host	3		
13	GND	Ground			1		
14	SCL	2-wire Serial interface clock	LVCMOS-I/O	Bi-directional	3	3 Open-Drain with pull- up resistor on Host	
15	VCC	+3.3V Power		Power from Host	2		
16	VCC	+3.3V Power		Power from Host	2		
17	LPWn/PRSn	Low-Power Mode / Module Present	Multi-Level	Bi-directional	3	See pin description for required circuit	
18	GND	Ground			1		
19	RX7n	Receiver Data Inverted	CML-O	Output to Host	3		
20	RX7p	Receiver Data Non-Inverted	CML-O	Output to Host	3		
21	GND	Ground			1		
22	RX5n	Receiver Data Inverted	CML-O	Output to Host	3		
23	RX5p	Receiver Data Non-Inverted	CML-O	Output to Host	3		
24	GND	Ground			1		
25	RX3n	Receiver Data Inverted	CML-O	Output to Host	3		
26	RX3p	Receiver Data Non-Inverted	CML-O	Output to Host	3		
27	GND	Ground		2	1		
28	RX1n	Receiver Data Inverted	CML-O	Output to Host	3		
29	RX1p	Receiver Data Non-Inverted	CML-O	Output to Host	3		
30	GND	Ground			1		



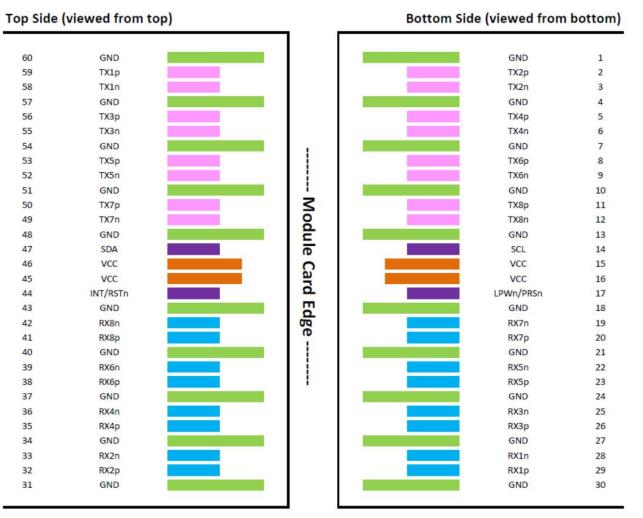
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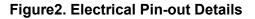
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31	GND	Ground			1	
32	RX2p	Receiver Data Non-Inverted	CML-O	Output to Host	3	
33	RX2n	Receiver Data Inverted	CML-O	Output to Host	3	
34	GND	Ground			1	
35	RX4p	Receiver Data Non-Inverted	CML-O	Output to Host	3	
36	RX4n	Receiver Data Inverted	CML-O	Output to Host	3	
37	GND	Ground			1	
38	RX6p	Receiver Data Non-Inverted	CML-O	Output to Host	3	
39	RX6n	Receiver Data Inverted	CML-O	Output to Host	3	
40	GND	Ground			1	
41	RX8p	Receiver Data Non-Inverted	CML-O	Output to Host	3	
42	RX8n	Receiver Data Inverted	CML-O	Output to Host	3	
43	GND	Ground			1	
44	INT/RSTn	Module Interrupt / Module Reset	Multi-Level	Bi-directional	3	See pin description for required circuit
45	VCC	+3.3V Power		Power from Host	2	
46	VCC	+3.3V Power		Power from Host	2	
47	SDA	2-wire Serial interface data	LVCMOS-I/O	Bi-directional	3	Open-Drain with pull- up resistor on Host
48	GND	Ground			1	
49	TX7n	Transmitter Data Inverted	CML-I	Input from Host	3	
50	TX7p	Transmitter Data Non-Inverted	CML-I	Input from Host	3	
51	GND	Ground			1	
52	TX5n	Transmitter Data Inverted	CML-I	Input from Host	3	
53	TX5p	Transmitter Data Non-Inverted	CML-I	Input from Host	3	
54	GND	Ground			1	
55	TX3n	Transmitter Data Inverted	CML-I	Input from Host	3	
56	TX3p	Transmitter Data Non-Inverted	CML-I	Input from Host	3	
57	GND	Ground			1	
58	TX1n	Transmitter Data Inverted	CML-I	Input from Host	3	
59	TX1p	Transmitter Data Non-Inverted	CML-I	Input from Host	3	
60	GND	Ground			1	



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INT/RSTn Pin

INT/RSTn is a dual function signal that allows the module to raise an interrupt to the host and also allows the host to reset the module. The circuit shown in Figure 13-3 enables multi-level signaling to provide direct signal control in both directions. Reset is an active-low signal on the host which is translated to an active-low signal on the module. Interrupt is an active high signal on the module which gets translated to an active-high signal on the host. The INT/RSTn signal operates in 3 voltage zones to indicate the state of Reset for the module and Interrupt for the host. Figure 13-2 shows these 3 zones. The host uses a voltage reference at 2.5 volts to determine the state of the H_INT signal and the module uses a voltage reference at 1.25V to determine the state of the M_RSTn signal.



LPWn/PRSn

LPWn/PRSn is a dual function signal that allows the host to signal Low Power mode and the module to indicate Module Present. The circuit shown in Figure 13-5 enables multi-level signaling to provide direct signal control in both directions. Low Power mode is an active low signal on the host which gets converted to an active-low signal on the module. Module Present is controlled by a pull-down resistor on the module which gets converted to an active-low logic signal on the host. The LPWn/PRSn signal operates in 3 voltage zones to indicate the state of Low Power mode for the module and Module Present for the host. Figure 13-4 shows these 3 zones. The host uses a voltage reference at 2.5 volts to determine the state of the H_PRSn signal and the module uses a voltage reference at 1.25V to determine the state of the M_LPWn signal.

Power Supply Filtering

The host board should use the power supply filtering shown in Figure3.

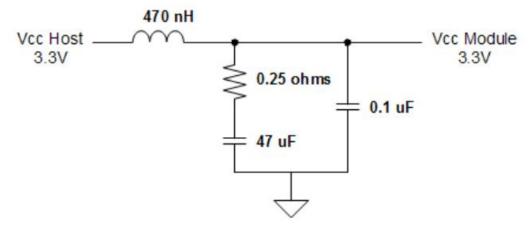


Figure 3. Host Board Power Supply Filtering

DIAGNOSTIC MONITORING INTERFACE

Digital diagnostics monitoring function is available on all Gigalight OSFP products. A 2-wire serial interface provides user to contact with module.

Memory Structure and Mapping

This limits the management memory that can be directly accessed by the host to 256 bytes, which is divided in Lower Memory (addresses 00h through 7Fh) and Upper Memory (addresses 80h through FFh).

A larger addressable management memory is required for all but the most basic modules. This is



supported by a structure of 128-byte pages, together with a mechanism for dynamically mapping any of the 128-byte pages from a larger internal management memory space into Upper Memory the host addressable space.

The addressing structure of the additional internal management memory is shown in Figure 4 The management memory inside the module is arranged as a unique and always host accessible address space of 128 bytes (Lower Memory) and as multiple upper address subspaces of 128 bytes each (Pages), only one of which is selected as host visible in Upper Memory. A second level of Page selection is possible for Pages for which several instances exist (e.g. where a bank of pages with the same Page number exists).

This structure supports a flat 256 byte memory for passive copper modules and permits timely access to addresses in the Lower Memory, e.g. Flags and Monitors. Less time critical entries, e.g. serial ID information and threshold settings, are available with the Page Select function in the Lower Page. For more complex modules which require a larger amount of management memory the host needs to use dynamic mapping of the various Pages into the host addressable Upper Memory address space, whenever needed.

Note: The management memory map has been designed largely after the QSFP memory map. This memory map has been changed in order to accommodate 4 electrical lanes and to limit the required memory space. The single address approach is used as found in QSFP. Paging is used in order to enable time critical interactions between host and module.

Supported Pages

A basic 256 byte subset of the Management Memory Map is mandatory for all CMIS compliant devices. Other parts are only available for paged memory modules, or when advertised by the module. See CMIS V4.0 for details regarding the advertisement of supported management memory spaces.

In particular, support of the Lower Memory and of Page 00h is required for all modules, including passive copper cables. These pages are therefore always implemented. Additional support for Pages 01h, 02h and bank 0 of Pages 10h and 11h is required for all paged memory modules.

Bank 0 of pages 10h-1Fh, provides lane-specific registers for the first 4 lanes, and each additional bank provides support for additional 4 lanes. Note, however, that the allocation of information over the banks may be page specific and may not to be related to grouping data for 4 lanes.

The structure allows address space expansion for certain types of modules by allocating additional Pages. Moreover, additional banks of pages.



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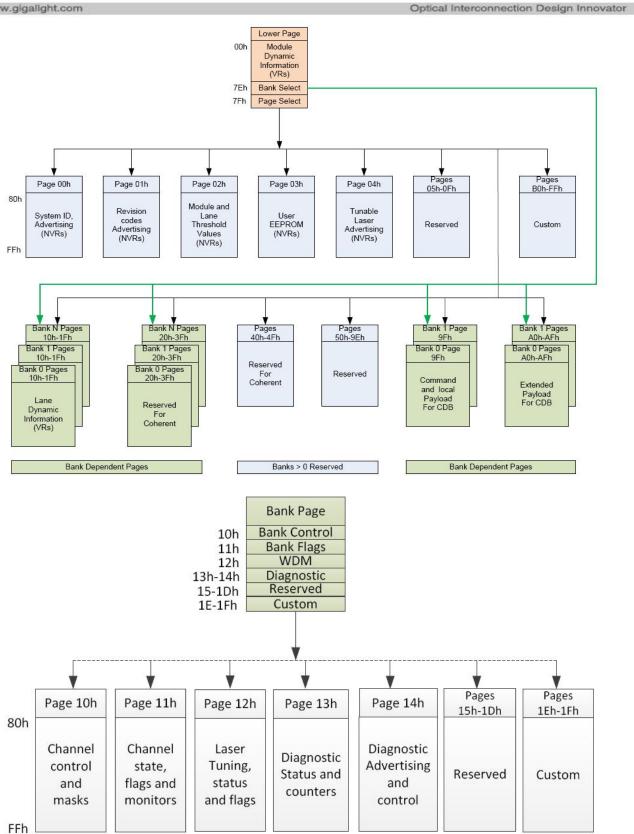


Figure4. OSFP Memory Map



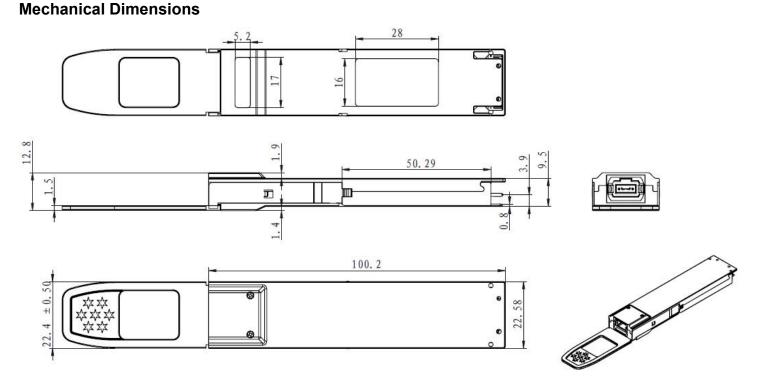


Figure 5. Mechanical Specifications

Regulatory Compliance

Gigalight GOP-SI401DR4C transceivers are Class 1 Laser Products. They meet the requirements of the following standards:

Feature	Standard
Laser Safety	IEC 60825-1:2014 (3 rd Edition) IEC 60825-2:2004/AMD2:2010 EN 60825-1-2014 EN 60825-2:2004+A1+A2
Electrical Safety	EN 62368-1: 2014 IEC 62368-1:2014 UL 62368-1:2014
Environmental protection	Directive 2011/65/EU with amendment(EU)2015/863
CE EMC	EN55032: 2015 EN55035: 2017 EN61000-3-2:2014 EN61000-3-3:2013



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FCC	FCC Part 15, Subpart B ANSI C63.4-2014	
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References

- 1. OSFP MSA
- 2. CMIS
- 3. IEEE802.3bs
- 4. OIF CEI-112G-VSR



Use of controls or adjustment or performance of procedures other than those specified herein may result in hazardous radiation exposure.

Ordering information

Part Number	Product Description			
GOP-SI401DR4C	OSFP-RHS, 400GBASE-DR4, 500m on Single mode Fiber (SMF),with DSP Power consumption <10W, MPO-12 connector.			

Important Notice

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Revision History

Revision	Date	Description
V0	Nov-24-2023	Advance Release.